



REVERSE VOLTAGE

FORWARD CURRENT

LITE-ON SEMICONDUCTOR G20120CTW

- 120 Volts

TO-220AB

- 20 Amperes

SCHOTTKY BARRIER RECTIFIERS

FEATURES

- Trench Schottky technology
- Low power loss, high efficiency
- Low forward drop voltage
- Qualified according to AEC-Q101 Rev_C
- · For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case: TO-220AB molded plastic
- · Case Material: "Green" molding compound, UL Flammability classification 94V-0,"Halogen-free".
- · Plastic package has UL flammability classification 94V-0
- Terminals: Matte Tin
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Polarity: As marked on the body
- Weight: 0.072 ounces, 2.0275 grams(Approximate)
- Mounting position: Any
- Max. mounting torque = 0.5 N.m (5.1 Kgf-cm)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

ABSOLUTE RATINGS

PARAMETER		SYMBOL	VALUE	UNIT
Maximum Repetitive Peak Reverse Voltage		V _{RRM}	120	V
Maximum DC Blocking Voltage		V _{DC}	120	V
Average Rectified Output Current per device	@Tc=130°C	١ _F	20	А
Non-repetitive Peak Forward Surge Current single half sine-wave	tp=8.3ms	I _{FSM}	120	А
Operating and Storage temperature range		T _{J,} T _{STG}	-55 to +150	°C

STATIC ELECTRICAL CHARACTERISTICS

Parameter	Test condition	Symbol	Тур.	Max.	Unit
Maximum Forward Voltage Note (4)	IF=10A @Tj=25°C IF=10A @Ti=125°C	VF	0.82 0.64	0.84 0.72	V
Maximum DC Reverse Current	VR=120V @Tj=25°C @Tj=125°C	IR	- 4	150 25	uA mA
Junction Capacitance per element	1MHz, VR=4V	Cj	430	-	pF

THERMAL CHARACTERISTICS

Parameter	SYMBOL	VALUE		UNIT
Typical thermal resistance Junction (Note 5 & 6)	R⊖ _{JC}	1.3		
	R⊖ _{JL}	2.0		°C/W
	R⊖ _{JA}	8.0		
Note :			REV5, Sep-2021, KT	HC115

Note :

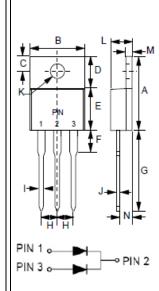
EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3).compliant. All applicable RoHS exemptions applied. (1)

See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. (2)Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm (3) antimony compounds.

300us Pulse Width, 2% Duty Cycle.

(5) Thermal Resistance Junction to Case, Lead and Ambient.

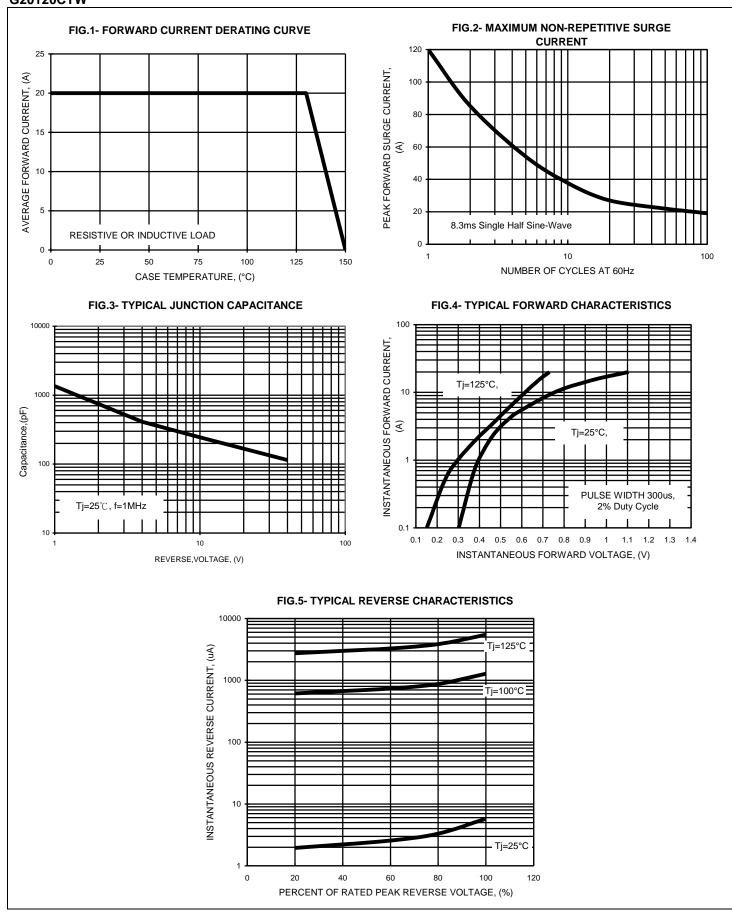
Device mounted on 100 x 100 x 2 mm Copper plate. (6)



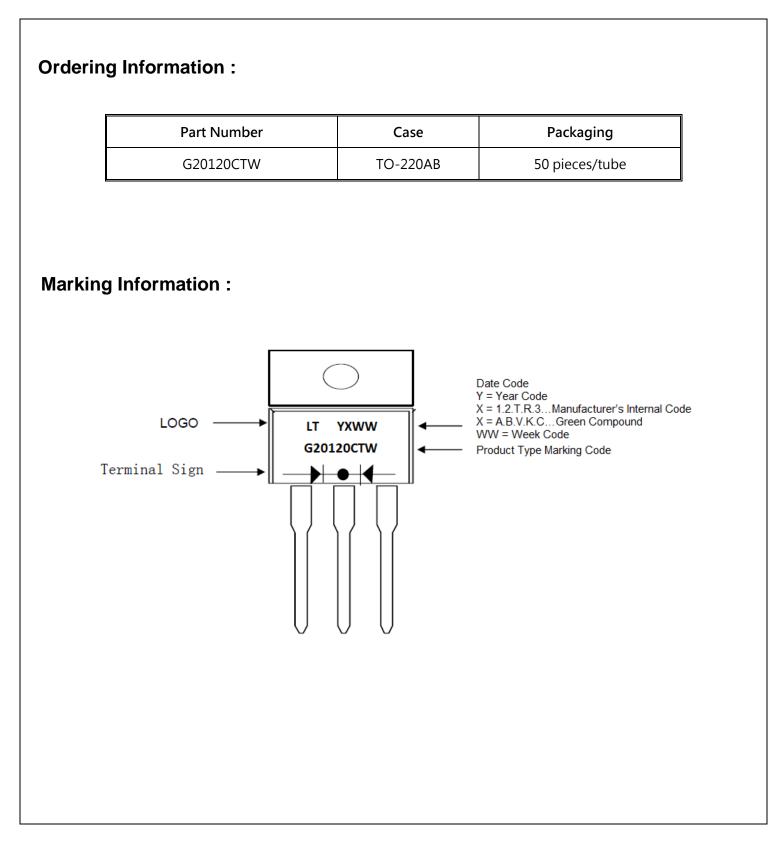
TO-220AB				
DIM	MIN	MAX		
А	14.40	15.20		
В	9.65	10.67		
C	2.54	3.43		
D	5.84	6.86		
E	8.26	9.28		
F	-	4.20		
G	12.70	14.73		
Н	2.29	2.79		
	0.51	1.14		
J	0.30	0.64		
К	3.53Ф	4.09Φ		
L	3.56	4.83		
Μ	1.14	1.40		
Ν	2.03	2.92		
0	1.14	1.70		
All Dimensions in millimeter				



LITE-ON SEMICONDUCTOR









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